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TO: Examiner Junghwa M. Im

OUR REF.: MICRON.172A

FIRM: United States Patent and Trademark Office

YOUR REF.: Appl. No. 09/945,065

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MICRON.172A

PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant : Ammar Derraa et al.  
 Appl. No. : 09/945,065  
 Filed : August 30, 2001  
 For : METAL SILICIDE ADHESION  
       LAYER FOR CONTACT  
       STRUCTURES  
 Examiner : Junghwa M. Im  
 Group Art Unit : 2811

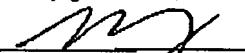
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Linda H. Liu, Reg. No. 51,240

Commissioner for Patents  
 P.O. Box 1450  
 Alexandria, VA 22313-1450

Dear Examiner Im:

Pursuant to our telephone conference today, enclosed is a copy of the Appellant's Reply Brief in response to the Examiner's Answer dated July 29, 2005. This Reply Brief is identical in content to the Reply Brief the Applicant filed with the PTO on August 30, 2004 in response to the Examiner's Answer dated June 30, 2004. The Examiner's Answer dated June 30, 2004 is identical in content to the Examiner's Answer dated July 29, 2005.

Please charge any additional fees, including any fees for additional extension of time, or credit overpayment to Deposit Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 5/2/2007

By:   
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MICRON.172A

PATENT

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Ammar Deraa et al.  
 Appl. No. : 09/945,065  
 Filed : August 30, 2001  
 For : METAL SILICIDE ADHESION  
       LAYER FOR CONTACT  
       STRUCTURES  
 Examiner : Junghwa M. Im  
 Group Art Unit : 2811

ON APPEAL TO THE BOARD OF PATENT APPEALS AND INTERFERENCES  
APPELLANT'S REPLY BRIEF

Commissioner for Patents  
 P.O. Box 1450  
 Alexandria, VA 22313-1450

Dear Sir:

Applicant, in the above-captioned patent application, reply to the Examiner's Answer mailed June 30, 2004. This Reply Brief is filed in triplicate.

REPLY

In the Examiner's Answer, the Examiner states that Appellant mainly argues "none of the references teach an integrated circuit contact structure having a metal silicide adhesion layer that functions both as an adhesion layer and a refractory metal silicide layer." The Examiner took the position that since Taguwa shows a titanium silicide layer formed between a titanium layer and a titanium nitride layer, Taguwa teaches a titanium silicide layer is a refractory metal silicide layer that also serves the function of enhancing adhesion between the titanium and titanium silicide.

Appellant respectfully disagrees with the Examiner's characterization of Appellant's main argument. Appellant would like to clarify its argument by emphasizing that none of the prior art references disclose an integrated circuit having a metal silicide adhesion layer that functions both as an adhesion layer and a refractory metal silicide layer *which serves to improve the contact at the interface between the metal and semiconductive active areas.*

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Appl. No. : 09/945,065  
Filed : August 30, 2001

MAY 03 2007

While Taguwa discloses a titanium silicide layer, Appellant notes that Taguwa's titanium silicide layer is interposed between the titanium and titanium nitride layers and therefore does not contact the semiconductor substrate. As such, Taguwa's titanium silicide layer could not possibly serve the function of a refractory metal silicide layer that improves the contact at the interface between the metal and semiconductive areas.

Appellant further submits that there is no motivation to combine the teachings in Taguwa with Thakur to form a structure having a metal silicide adhesion layer that also functions as a refractory metal silicide layer used to improve the contact between the metal and semiconductive active areas. Taguwa is directed to a contact structure having layers of titanium silicide interposed between titanium and titanium nitride to absorb thermal stress therebetween. Thakur discloses forming a refractory metal silicide layer in the contact area using conventional dopant implant processes. Appellant submits that it would be counter-intuitive to form an additional layer of metal silicide directly on the refractory metal silicide already formed in the contact region in Thakur.

In accordance with the above remarks and the remarks made in the Appeal Brief filed October 20, 2003, the Appellant respectfully submits that the invention defined by Claims 1-4 and 6-20 is not made obvious by Taguwa, Thakur, or a combination of the two, and that these claims are in condition for allowance.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 5/2/2007

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